

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

The NCEP0135AFuses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **General Features**

V<sub>DS</sub> =100V,I<sub>D</sub> =35A

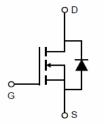
$$\begin{split} R_{DS(ON)} = &18m\Omega \text{ (typical) } \textcircled{@} \text{ } V_{GS} = &10V \\ R_{DS(ON)} = &22m\Omega \text{ (typical) } \textcircled{@} \text{ } V_{GS} = &4.5V \end{split}$$

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



Schematic Diagram



Marking and pin assignment



TO-220F top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0135AF	NCEP0135AF	TO-220F	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>G</sub> S	±20	V
Drain Current-Continuous	I <sub>D</sub>	35	Α
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	24.7	А
Pulsed Drain Current (Note 1)	I <sub>DM</sub>	180	А
Maximum Power Dissipation	P <sub>D</sub>	35	W
Derating factor		0.23	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	200	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C



## http://www.ncepower.com

# NCEP0135AF

## **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	4.3	°C/W	
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

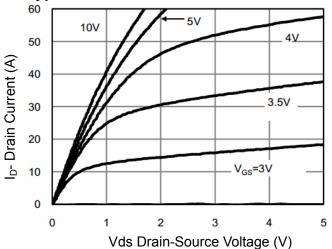
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	2.0	2.8	V
Drain-Source On-State Resistance	Б	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	18	23	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	22	27	mΩ
Forward Transconductance	<b>g</b> <sub>FS</sub>	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	35	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -F0\/\/ -0\/	-	1600	-	PF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V, F=1.0MHz	-	139	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	11	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	6	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50V, $I_D$ =20A	-	2	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =1.6 $\Omega$	-	18	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	2	-	nS
Total Gate Charge	Qg	V -50VI -20A	-	26	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=50V,I_{D}=20A,$	-	7.4		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	3.8		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =35A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	35	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = 20A	-		26	nS
Reverse Recovery Charge	Qrr	$di/dt = 500A/\mu s^{(Note3)}$	-		98	nC

#### Notes:

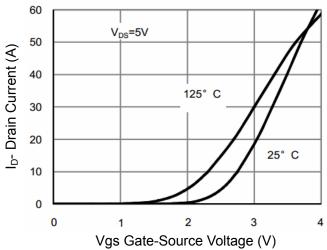
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=20V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$



### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

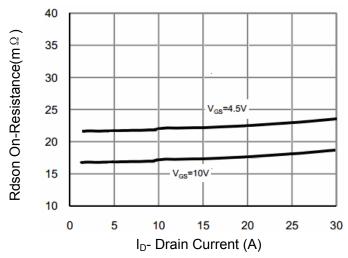
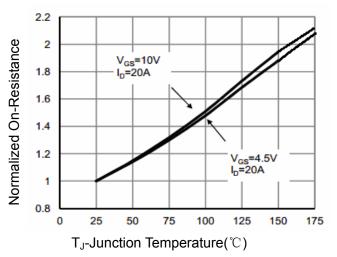


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

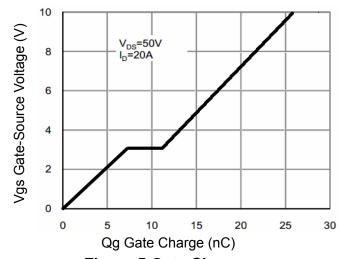


Figure 5 Gate Charge

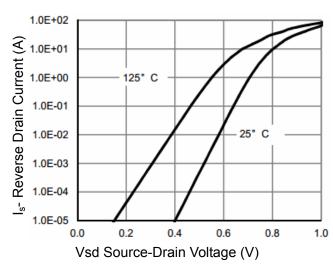


Figure 6 Source- Drain Diode Forward



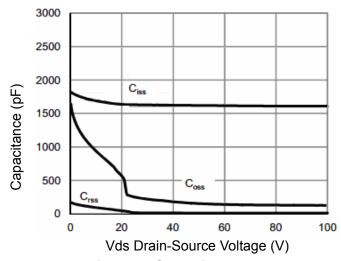


Figure 7 Capacitance vs Vds

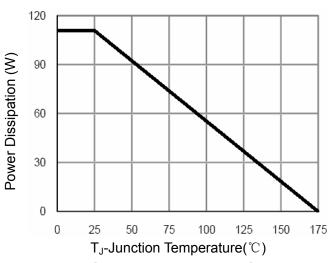
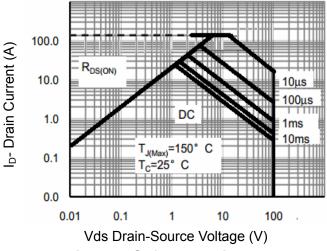


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

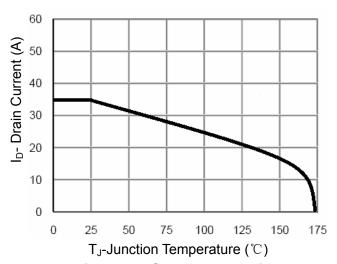


Figure 10 Current De-rating

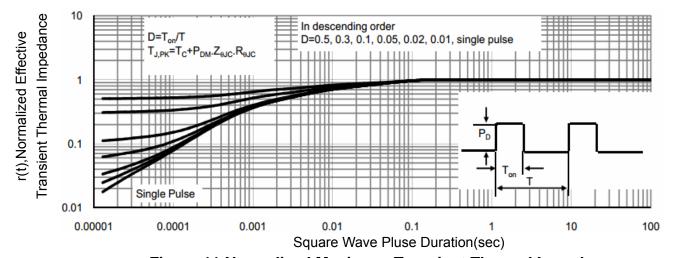
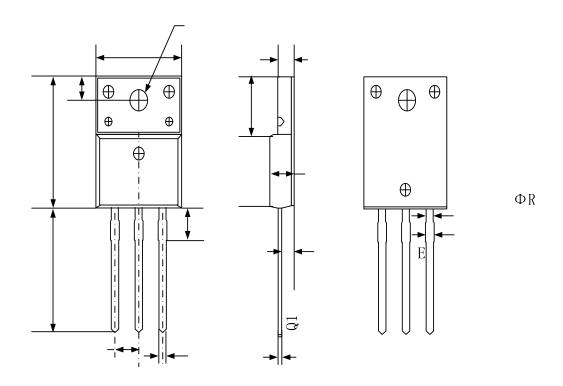


Figure 11 Normalized Maximum Transient Thermal Impedance



## **TO-220F Package Information**



Symbol	Dimensions I	In Millim <u>e</u> ters	Dimensions In Inches		
- Cymbol	Min.	Max.	Min.	Max.	
А	4.50	4.83	0. 18	0. 19	
b	0.70	0.91	0. 03	0. 04	
b1	1.20	1.47	0.05	0.06	
b2	1.10	1.38	0.04	0. 05	
С	0.45	0.63	0.02	0. 02	
D	15.67	16.07	0.62	0. 63	
е	2.54 BSC		0.10 BSC		
E	9.96	10.36	0. 39	0. 41	
F	2.34	2.74	0.09	0. 11	
G	6.48	6.90	0. 26	0. 27	
L	12.68	13.30	0. 50	0. 52	
L1	3.13	3.50	0. 12	0. 14	
Q	2.56	2.93	0. 10	0. 12	
Q1	3.20	3.40	0. 13	0. 13	
ФК	3.08	3.28	0. 12	0. 13	

2x€

3xb

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